NSN 5961-00-550-8619

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-550-8619 **Inclosure Material:** Metal **Terminal Length:** 2.000 inches **Mounting Method:** Terminal **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1200.0 nonrepetitive peak reverse voltage, peak total value **Current Rating Per Characteristic:** 12.00 amperes forward current, total rms megahertz **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Design analysis **Nuclear Hardness Critical Feature:** Hardened **Terminal Type And Quantity:** 1 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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